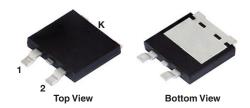


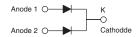
## Vishay General Semiconductor

# Dual High Voltage TMBS® (Trench MOS Barrier Schottky) Rectifier

### eSMP® Series



SMPD (TO-263AC)



| PRIMARY CHARACTERISTICS                  |                 |  |  |
|--|-----------------|--|--|
| I <sub>F(AV)</sub>                       | 2 x 5.0 A       |  |  |
| $V_{RRM}$                                | 170 V           |  |  |
| I <sub>FSM</sub>                         | 100 A           |  |  |
| $V_F$ at $I_F = 5.0$ A ( $T_A = 125$ °C) | 0.67 V          |  |  |
| T <sub>J</sub> max.                      | 175 °C          |  |  |
| Package                                  | SMPD (TO-263AC) |  |  |
| Circuit configurations                   | Common cathode  |  |  |

#### **FEATURES**



High efficiency operation

 Meets MSL level 1, J-STD-020, LF maximum peak of 260 °C

· Low forward voltage drop, low power losses

HALOGEN FREE

AEC-Q101 qualified available

· Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

#### TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

#### **MECHANICAL DATA**

Case: SMPD (TO-263AC)

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Base P/NHM3 halogen-free, RoHS-compliant, and AEC-Q101 qualified

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 and HM3 suffix meets JESD 201 class 2 whisker test

Polarity: As marked

| MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)          |            |                               |             |      |  |
|--|------------|-------------------------------|-------------|------|--|
| PARAMETER  |            | SYMBOL                        | V10D170C    | UNIT |  |
| Device marking code  |            |                               | V10D170C    |      |  |
| Maximum repetitive peak reverse voltage                                  |            | $V_{RRM}$                     | 170         | V    |  |
| Maximum average forward rectified current (fig. 1)                       | per device | I <sub>F(AV)</sub>            | 10          | А    |  |
|  | per diode  |                               | 5           | _ ^  |  |
| Peak forward surge current 8.3 ms single half superimposed on rated load | sine-wave  | I <sub>FSM</sub>              | 100         | А    |  |
| Operating junction temperature range                                     |            | T <sub>J</sub> <sup>(1)</sup> | -40 to +175 | °C   |  |
| Storage temperature range  |            | T <sub>STG</sub>              | -55 to +175 | °C   |  |

#### Note

<sup>(1)</sup> The heat generated must be less than the thermal conductivity from junction-to-ambient:  $dP_D/dT_{cl} < 1/R_{b,lA}$ 



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| <b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted) |                        |                         |                               |       |      |      |
|---|------------------------|-------------------------|-------------------------------|-------|------|------|
| PARAMETER   | TEST CONDITIONS        |                         | SYMBOL                        | TYP.  | MAX. | UNIT |
| Instantaneous forward voltage per diode   | I <sub>F</sub> = 2.5 A | T <sub>A</sub> = 25 °C  | V <sub>F</sub> <sup>(1)</sup> | 0.75  | -    | V    |
|   | I <sub>F</sub> = 5 A   |                         |                               | 0.82  | 0.9  |      |
|   | I <sub>F</sub> = 2.5 A | T <sub>A</sub> = 125 °C |                               | 0.6   | -    |      |
|   | I <sub>F</sub> = 5 A   |                         |                               | 0.67  | 0.74 |      |
| Reverse current at rated $V_R$ per diode  | V <sub>R</sub> = 140 V | T <sub>A</sub> = 25 °C  | I <sub>R</sub> <sup>(2)</sup> | 0.001 | -    | mA   |
|   |                        | T <sub>A</sub> = 125 °C |                               | 0.5   | -    | mA   |
|   | V <sub>R</sub> = 170 V | T <sub>A</sub> = 25 °C  |                               | -     | 0.05 | mA   |
|   | V <sub>R</sub> = 170 V | T <sub>A</sub> = 125 °C |                               | 1     | 3    | mA   |
| Typical junction capacitance  | 4.0 V, 1 MHz           |                         | CJ                            | 280   | -    | pF   |

#### **Notes**

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 5 ms

| THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted) |                         |                 |      |
|---|-------------------------|-----------------|------|
| PARAMETER   | SYMBOL                  | SYMBOL V10D170C |      |
| Typical thermal resistance per device                                   | R <sub>0</sub> JC (1)   | 2.5             | °C/W |
| rypical thermal resistance per device                                   | R <sub>0JA</sub> (2)(3) | 58              | C/VV |

#### **Notes**

- (1) Mounted on infinite heatsink
- $^{(2)}$  The heat generated must be less than the thermal conductivity from junction-to-ambient:  $dP_D/dT_J < 1/R_{\theta JA}$  junction-to-mount
- (3) Free air, without heatsink

| ORDERING INFORMATION (Example) |                 |              |               |                                    |  |
|--------------------------------|-----------------|--------------|---------------|------------------------------------|--|
| PREFERRED P/N                  | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE                      |  |
| V10D170C-M3/I                  | 0.55            | I            | 2000/reel     | 13" diameter plastic tape and reel |  |
| V10D170CHM3/I (1)              | 0.55            | I            | 2000/reel     | 13" diameter plastic tape and reel |  |

#### Note

(1) AEC-Q101 qualified

### **RATINGS AND CHARACTERISTICS CURVES** (T<sub>A</sub> = 25 °C unless otherwise noted)

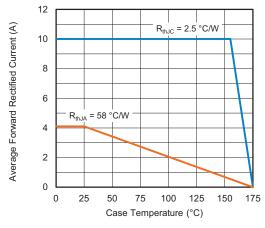


Fig. 1 - Forward Current Derating Curve

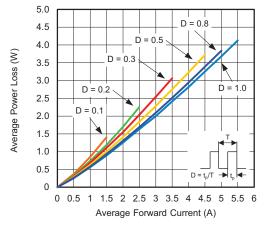


Fig. 2 - Forward Power Loss Characteristics



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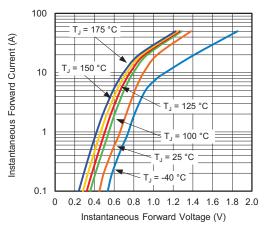


Fig. 3 - Typical Instantaneous Forward Characteristics

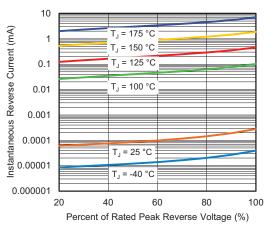


Fig. 4 - Typical Reverse Characteristics

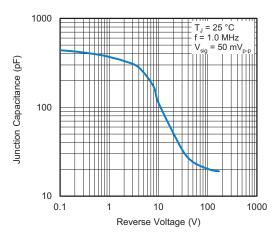


Fig. 5 - Typical Junction Capacitance

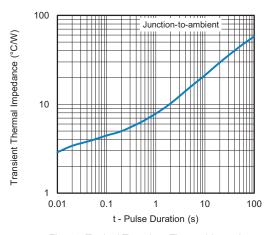


Fig. 6 - Typical Transient Thermal Impedance

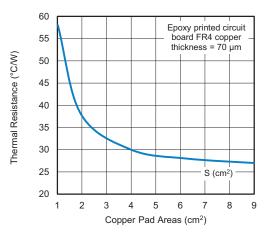
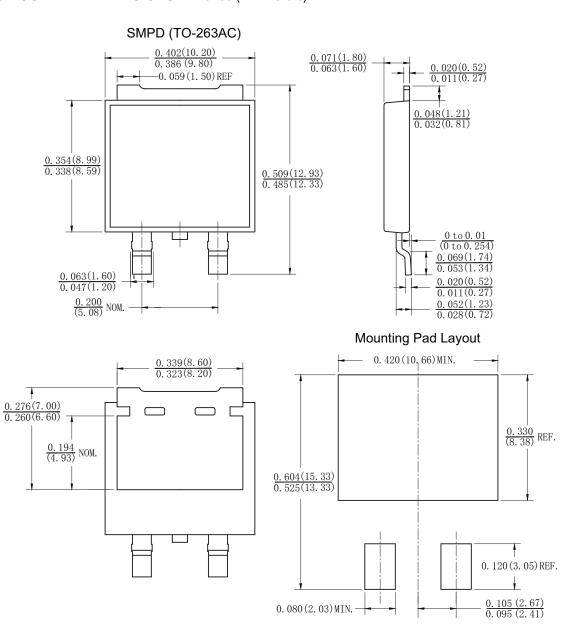


Fig. 7 - Thermal Resistance Junction-to-Ambient vs. Copper Pad Areas



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### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)





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